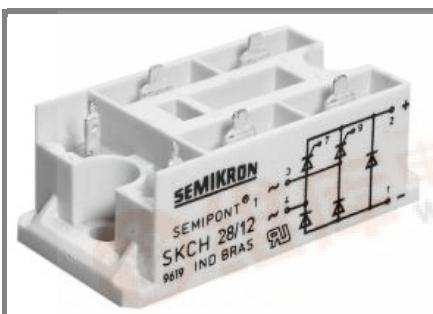


SKCH 28



SEMIPONT® 1

Controllable Bridge Rectifiers

SKCH 28

Features

- Sturdy isolated metal baseplate
- Fast-on terminals with solder tips
- Suitable for wave soldering
- High surge current rating
- UL recognized, file no. E 63 532

Typical Applications

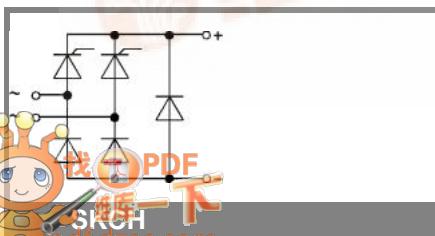
- Controllable single phase rectifier
- DC power supplies
- DC motor controllers
- DC motor field controllers

1) Painted metal shield of minimum 250 x 250 x 1 mm: $R_{th(c-a)} = 1,85 \text{ K/W}$

2) Freely suspended or mounted on insulator

| V_{RSM} V | V_{RRM}, V_{DRM} V | $I_D = 28 \text{ A}$ (full conduction) ($T_c = 89^\circ\text{C}$) |
|----------------|-------------------------|--|
| 400 | 400 | SKCH 28/04 |
| 600 | 600 | SKCH 28/06 |
| 800 | 800 | SKCH 28/08 |
| 1200 | 1200 | SKCH 28/12 |
| 1400 | 1400 | SKCH 28/14 |

| Symbol | Conditions | Values | Units |
|--------------------|---|----------------------------|--------------------------------------|
| I_D | $T_c = 85^\circ\text{C}$ $T_a = 45^\circ\text{C}$; chassis ¹⁾ $T_a = 45^\circ\text{C}$; P5A/100 $T_a = 45^\circ\text{C}$; P13A/125 $T_a = 45^\circ\text{C}$; P1A/120 | 30 13 15 16 23 | A A A A A |
| I_{TSM}, I_{FSM} | $T_{vj} = 25^\circ\text{C}; 10 \text{ ms}$ $T_{vj} = 125^\circ\text{C}; 10 \text{ ms}$ | 320 280 | A A |
| i^2t | $T_{vj} = 25^\circ\text{C}; 8,3 \dots 10 \text{ ms}$ $T_{vj} = 125^\circ\text{C}; 8,3 \dots 10 \text{ ms}$ | 510 390 | A ² s A ² s |
| V_T | $T_{vj} = 25^\circ\text{C}; I_T=75 \text{ A}$ | max. 2,25 | V |
| $V_{T(TO)}$ | $T_{vj} = 125^\circ\text{C};$ | max. 1 | V |
| r_T | $T_{vj} = 125^\circ\text{C}$ | max. 16 | mΩ |
| I_{DD}, I_{RD} | $T_{vj} = 125^\circ\text{C}; V_{DD} = V_{DRM}; V_{RD} = V_{RRM}$ | max. 8 | mA |
| t_{gd} | $T_{vj} = 25^\circ\text{C}; I_G = 1 \text{ A}; di_G/dt = 1 \text{ A}/\mu\text{s}$ | 1 | μs |
| t_{gr} | $V_D = 0,67 \cdot V_{DRM}$ | 1 | μs |
| $(dv/dt)_{cr}$ | $T_{vj} = 125^\circ\text{C}$ | max. 500 | V/μs |
| $(di/dt)_{cr}$ | $T_{vj} = 125^\circ\text{C}; f = 50 \text{ Hz}$ | max. 50 | A/μs |
| t_q | $T_{vj} = 125^\circ\text{C}; \text{typ.}$ | 80 | μs |
| I_H | $T_{vj} = 25^\circ\text{C}; \text{typ. / max.}$ | 50 / 150 | mA |
| I_L | $T_{vj} = 25^\circ\text{C}; R_G = 33 \Omega$ | 100 / 300 | mA |
| V_{GT} | $T_{vj} = 25^\circ\text{C}; \text{d.c.}$ | min. 2 | V |
| I_{GT} | $T_{vj} = 25^\circ\text{C}; \text{d.c.}$ | min. 100 | mA |
| V_{GD} | $T_{vj} = 125^\circ\text{C}; \text{d.c.}$ | max. 0,25 | V |
| I_{GD} | $T_{vj} = 125^\circ\text{C}; \text{d.c.}$ | max. 3 | mA |
| $R_{th(j-c)}$ | per thyristor / diode | 1,8 | K/W |
| | total | 0,45 | K/W |
| $R_{th(c-s)}$ | total | 0,1 | K/W |
| $R_{th(j-a)}$ | total ²⁾ | 15 | K/W |
| T_{vj} | | - 40 ... + 125 | °C |
| T_{stg} | | - 40 ... + 125 | °C |
| V_{isol} | a. c. 50 Hz; r.m.s.; 1 s / 1 min. | 3600 (3000) | V |
| M_s | case to heatsink | 2 | Nm |
| M_t | | n.a. | Nm |
| m | | 66 | g |
| Case | SKCH | G 25 | |



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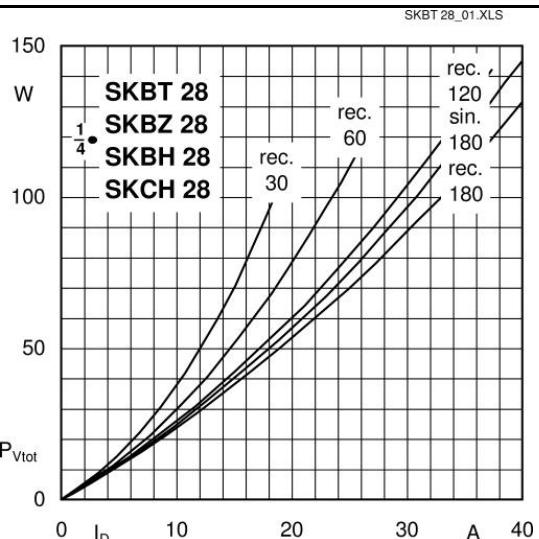


Fig. 1 Power dissipation vs. output current

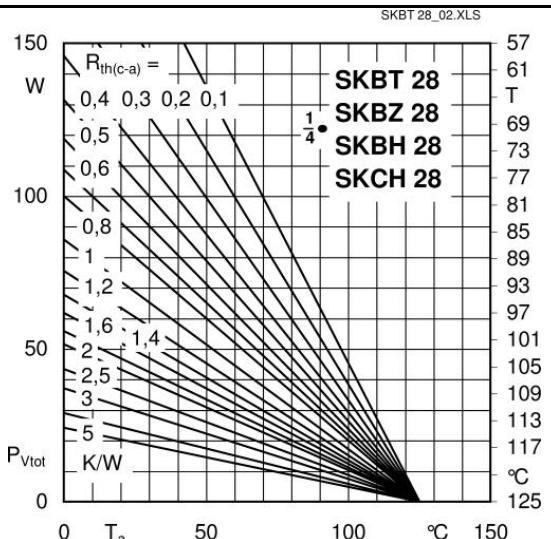


Fig. 2 Power dissipation vs. case temperature

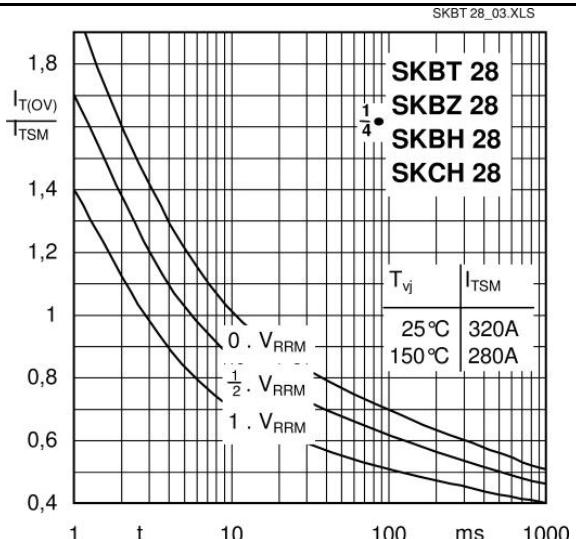


Fig. 5 Surge overload characteristics vs. time

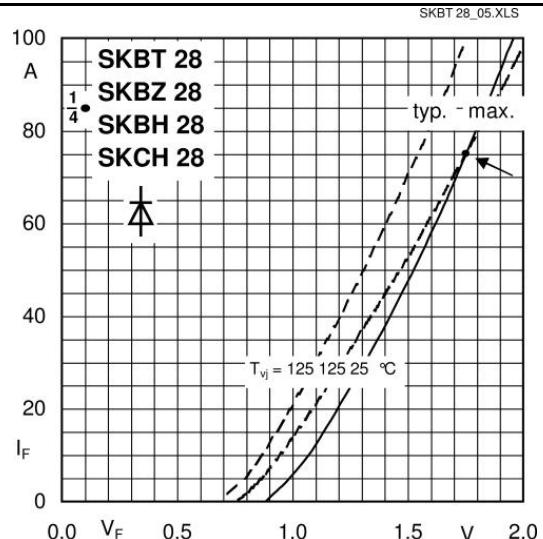


Fig. 9 Forward characteristics of a diode arm

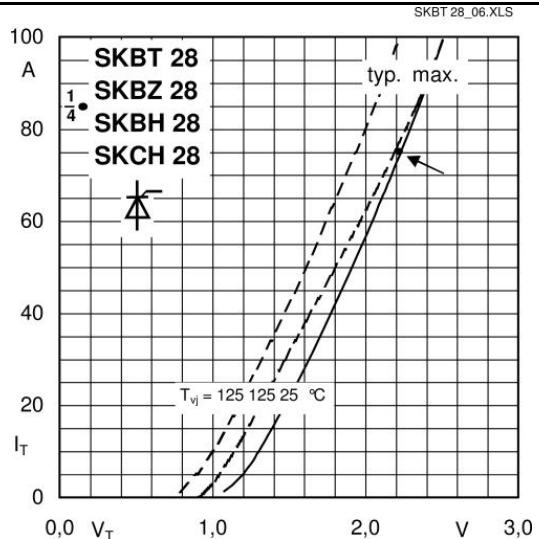


Fig. 10 On-state characteristics of a thyristor arm

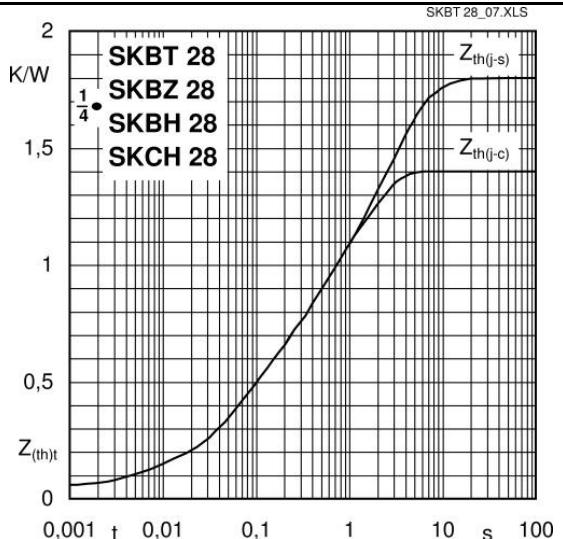


Fig. 12 Transient thermal impedance vs. time

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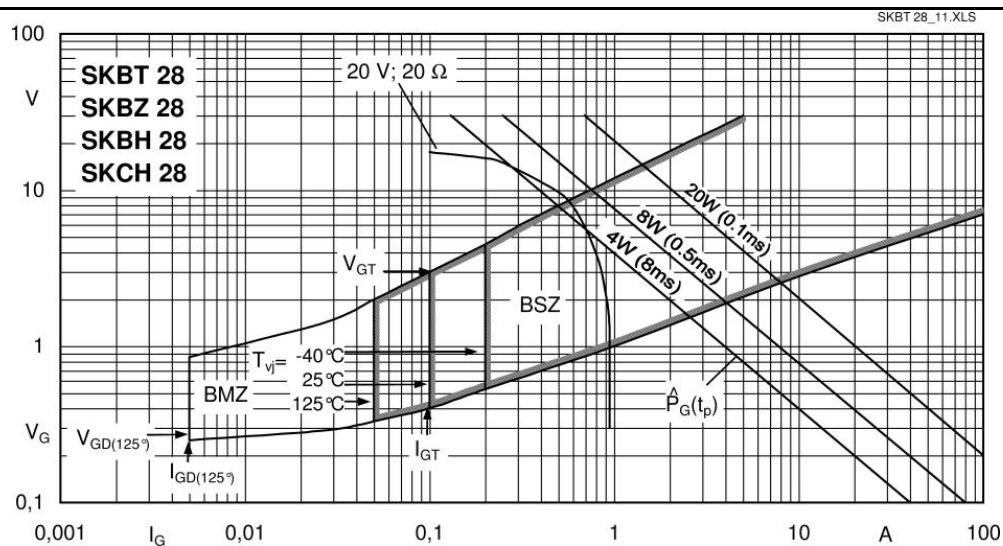
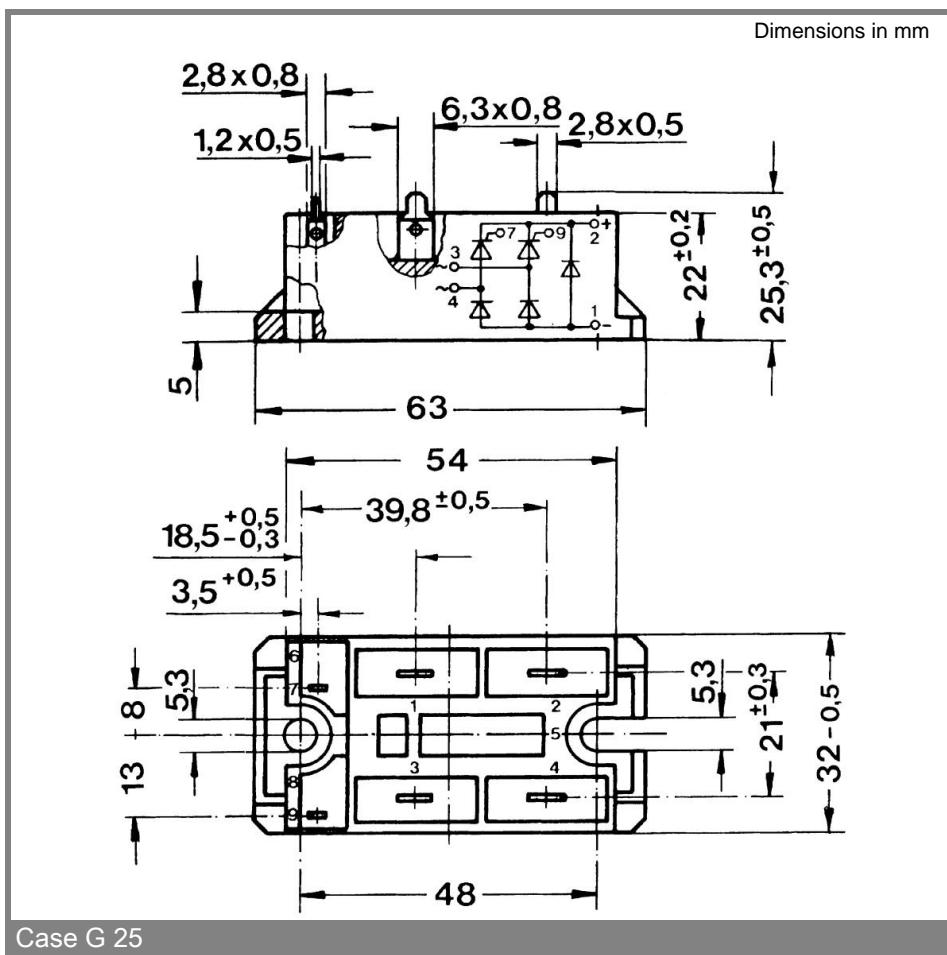


Fig. 11 Gate characteristics of a thyristor device



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